

FMS2023

Website: www.filtronic.com

Preliminary Datasheet v2.2

DC-20 GHz MMIC Low Loss SPST Absorptive Switch

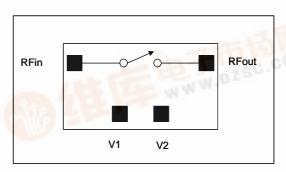
FEATURES:

- Available in die form
- Non-reflective design
- Low Insertion loss 1 dB at 20 GHz typical
- Very high isolation 50 dB at 20 GHz typical
- Excellent low control voltage performance

GENERAL DESCRIPTION:

The FMS2023 is a low loss high isolation broadband single pole single throw Gallium Arsenide switch designed for use in broadband communications instrumentation and electronic warfare applications. The die is fabricated using the Filtronic FL05 0.5µm switch process technology that offers leading edge performance optimised for switch applications.

FUNCTIONAL SCHEMATIC:



TYPICAL APPLICATIONS:

- Broadband communications
- Instrumentation
- Electronic warfare (ECM, ESM)

ELECTRICAL SPECIFICATIONS (based on on-wafer measurements):

PARAMETER	CONDITIONS		Түр	Max	Units
Insertion Loss	(DC-10) GHz, Small Signal		0.7		dB
Insertion Loss	(10-15) GHz, Small Signal		0.8		dB
Insertion Loss	(15-20) GHz, Small Signal		1		dB
Isolation	(DC-10) GHz, Small Signal		47	411	dB
Isolation	(10-15) GHz, Small Signal	12 (1)	47	W.D.	dB
Isolation	(15-20) GHz, Small Signal	1137	50		dB
Input Return Loss (on state)	(DC-20) GHz, Small Signal		20		dB
Output Return Loss (on state)	(DC-20) GHz, Small Signal		22		dB
Output Return Loss (off state)	(DC-20) GHz, Small Signal		12		ns
P1dB	-5V control		26		dBm

Note: T_{AMBIENT} = 25°C, Vctrl = 0V/-5V



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ABSOLUTE MAXIMUM RATINGS:

PARAMETER	SYMBOL	ABSOLUTE MAXIMUM
Max Input Power	Pin	+38dBm
Operating Temp	Toper	-40°C to +100°C
Storage Temp	Tstor	-55°C to +150°C

Note: Exceeding any one of these absolute maximum ratings may cause permanent damage to the device.

TRUTH TABLE:

Contr	OL LINE	RF PATH
V1	V2	RFIN-RF0
-5V	0V	On (Low Loss)
0V	-5V	Off (Isolation)

Note: $-5V \pm 0.2V$; $0V \pm 0.2V$

PAD LAYOUT:

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PAD NAME	DESCRIPTION	PIN COORDINATES (µm)
RFIN	RFIN	141,587
RFO	RFOUT	1789,587
V1	V1	901,161
V2	V2	1101,161

Note: Co-ordinates are referenced from the bottom left hand corner of the die to the centre of bond pad opening

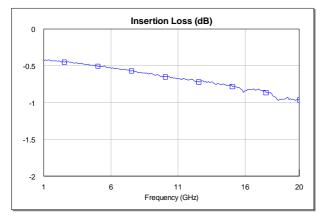
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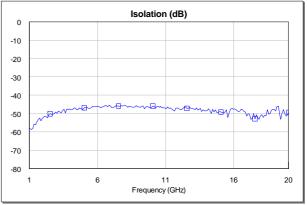
DIE SIZE (μm)	DIE THICKNESS (μm)	MIN. BOND PAD PITCH (μm)	Min. Bond pad Opening (μm x μm)
1910 x 1110	100	150	116 x 116



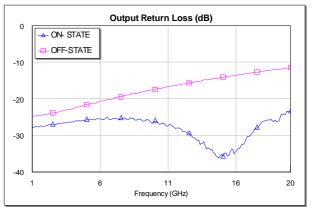
TYPICAL MEASURED PERFORMANCE ON WAFER:

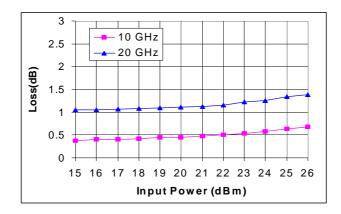
Note: Measurement Conditions VCTRL= -5V (low) & 0V (high), TAMBIENT = 25°C unless otherwise stated















PREFERRED ASSEMBLY INSTRUCTIONS:

GaAs devices are fragile and should be handled with great care. Specially designed collets should be used where possible.

The back of the die is metallised and the recommended mounting method is by the use of solder or conductive epoxy. If epoxy is selected then it should be applied to the attachment surface uniformly and sparingly to avoid encroachment of epoxy on to the top face of the die and ideally should not exceed half the chip height. For automated dispense Ablestick LMISR4 is recommended and for manual dispense Ablestick 84-1 LMI or 84-1 LMIT are recommended. These should be cured at a temperature of 150°C for 1 hour in an oven especially set aside for epoxy curing only. If possible the curing oven should be flushed with dry nitrogen.

This part has gold (Au) bond pads requiring the use of gold (99.99% pure) bondwire. It is recommended that 25.4µm diameter gold wire be used. Thermosonic ball bonding is preferred. A nominal stage temperature of 150°C and a bonding force of 40g has been shown to give effective results for 25µm wire. Ultrasonic energy shall be kept to a minimum. For this bonding technique, stage temperature should not be raised above 200°C and bond force should not be raised above 60g. bonding Thermosonic wedge thermocompression wedge bonding can also be used to achieve good wire bonds.

Bonds should be made from the die first and then to the mounting substrate or package. The physical length of the bondwires should be minimised especially when making RF or ground connections.

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HANDLING PRECAUTIONS:



To avoid damage to the devices care should be exercised during handling. Proper Electrostatic Discharge (ESD) precautions should be observed at all stages of storage, handling, assembly, and testing. These devices should be treated as Class 1A (0-500 V) as defined in JEDEC Standard No. 22-A114. Further information on ESD control measures can be found in MIL-STD-1686 and MIL-HDBK-263.

APPLICATION NOTES & DESIGN DATA:

Application Notes and design data including Sparameters are available; please contact Filtronic Compound Semiconductors Ltd.

DISCLAIMERS:

This product is not designed for use in any space based or life sustaining/supporting equipment.

ORDERING INFORMATION:

PART NUMBER	DESCRIPTION
FMS2023-000	Die in Waffle-pack
	(Gel-pak available on request)

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